Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

Vishay Semiconductor/Diodes Division
VS-86HF100

For any questions, you can email us directly:
sales@integrated-circuit.com

Standard Recovery Diodes, (Stud Version), 85 A

DO-203AB (DO-5)

FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600 V V_{RRM}
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

RoHS COMPLIANT

TYPICAL APPLICATIONS

- Battery chargers
- Converters
- Power supplies
- Machine tool controls
- Welding

PRODUCT SUMMARY	
$I_{F(AV)}$	85 A

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	85HF(R)		UNITS
		10 TO 120	140/160	
$I_{F(AV)}$		85		A
	T_C	140	110	°C
$I_{F(RMS)}$		133		A
I_{FSM}	50 Hz	1700		A
	60 Hz	1800		
I^2t	50 Hz	14 500		A^2s
	60 Hz	13 500		
V_{RRM}	Range	100 to 1200	1400/1600	V
T_J		- 65 to 180	- 65 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM}, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
85HF(R)	10	100	200	9
	20	200	300	
	40	400	500	
	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	4.5
	160	1600	1700	

85HF(R) Series

Vishay Semiconductors

Standard Recovery Diodes,
(Stud Version), 85 A

FORWARD CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS			85HF(R) 10 to 120	85HF(R) 140/160	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave			85		A
					140	110	°C
Maximum RMS forward current	$I_{F(RMS)}$				133		A
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	1700		A
		t = 8.3 ms			1800		
		t = 10 ms	100 % V_{RRM} reapplied		1450		
		t = 8.3 ms			1500		
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied		14 500		A^2s
		t = 8.3 ms			13 500		
		t = 10 ms	100 % V_{RRM} reapplied		10 500		
		t = 8.3 ms			9400		
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied			16 000		$A^2\sqrt{s}$
Value of threshold voltage (up to 1200 V)	$V_{F(TO)}$	$T_J = T_J$ maximum			0.68		V
Value of threshold voltage (for 1400 V, 1600 V)					0.69		
Value of forward slope resistance (up to 1200 V)	r_f	$T_J = T_J$ maximum			1.62		mΩ
Value of forward slope resistance (for 1400 V, 1600 V)					1.75		
Maximum forward voltage drop	V_{FM}	I_{pk} = 267 A, T_J = 25 °C, t_p = 400 µs rectangular wave			1.2	1.4	V

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	85HF(R) 10 to 120	85HF(R) 140/160	UNITS
Maximum junction operating and storage temperature range	T_J, T_{Stg}		- 65 to 180	- 65 to 150	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.35		K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased	0.25		
Maximum shock (1)			1500		g
Maximum constant vibration (1)		50 Hz	20		
Maximum constant acceleration (1)		Stud outwards	5000		
Maximum allowable mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on nut (2)	3.4 (30)		N · m (lbf · in)
		Lubricated thread, tighting on nut (2)	2.3 (20)		
		Not lubricated thread, tighting on hexagon (3)	4.2 (37)		
		Lubricated thread, tighting on hexagon (3)	3.2 (28)		
Approximate weight		Unleaded device	17		g
			0.6		oz.
Case style		See dimensions - link at the end of datasheet	DO-203AB (DO-5)		

Notes
(1) Available only for 88HF
(2) Recommended for pass-through holes
(3) Recommended for holed threaded heatsinks

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.10	0.08	$T_J = T_J$ maximum	K/W
120°	0.11	0.11		
90°	0.13	0.13		
60°	0.17	0.17		
30°	0.26	0.26		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

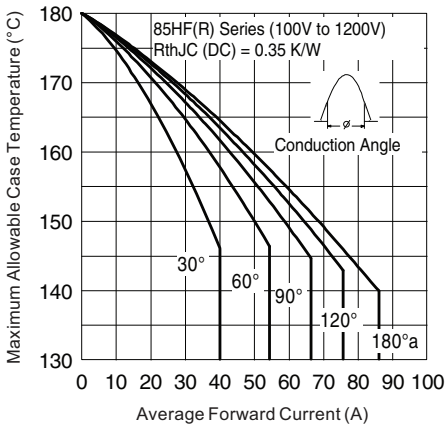


Fig. 1 - Current Ratings Characteristics

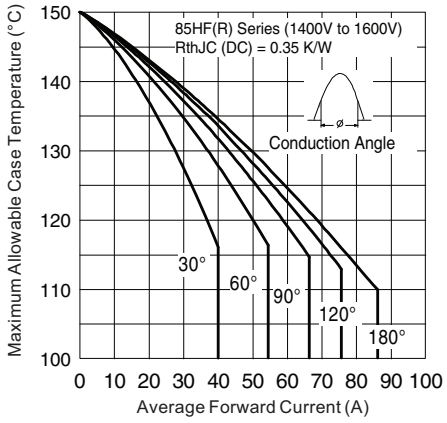


Fig. 3 - Current Ratings Characteristics

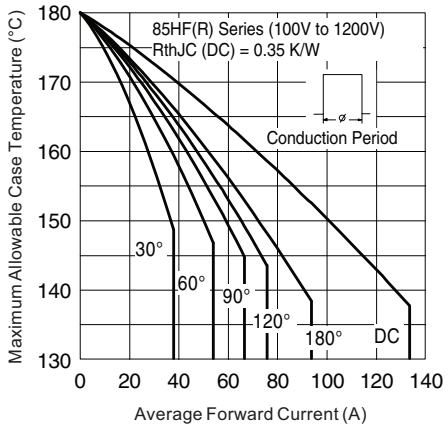


Fig. 2 - Current Ratings Characteristics

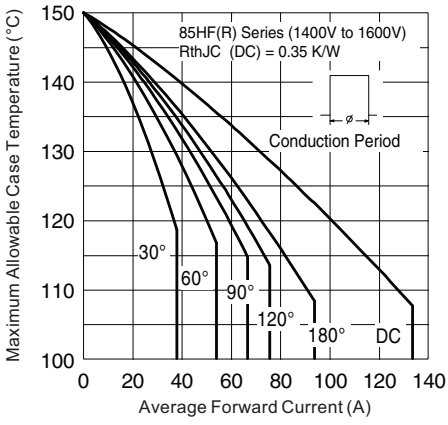


Fig. 4 - Current Ratings Characteristics

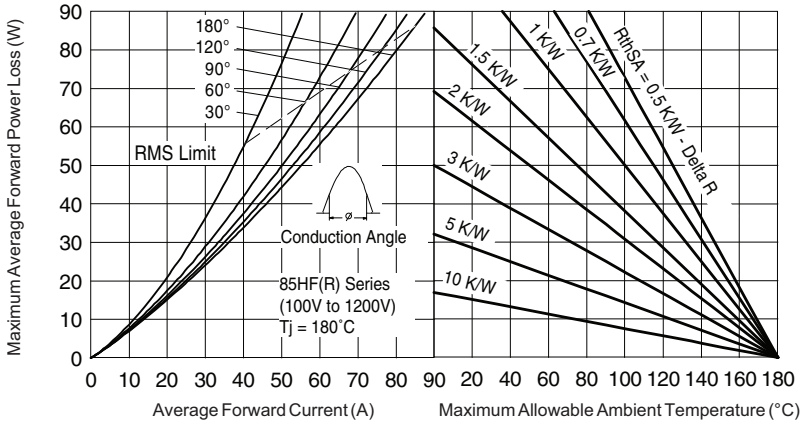


Fig. 5 - Forward Power Loss Characteristics

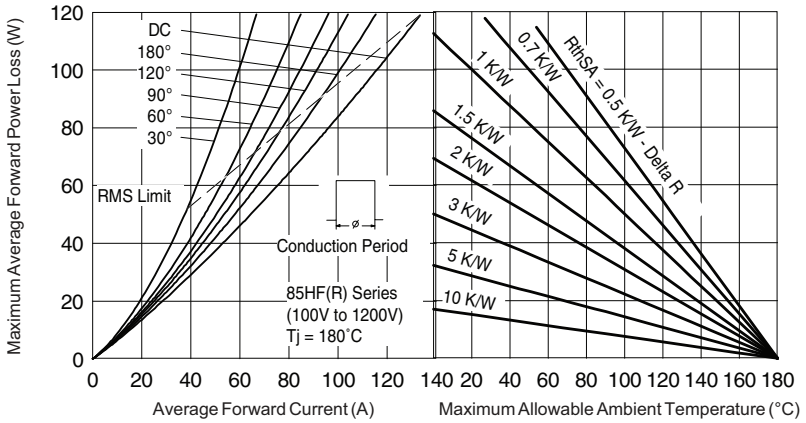


Fig. 6 - Forward Power Loss Characteristics

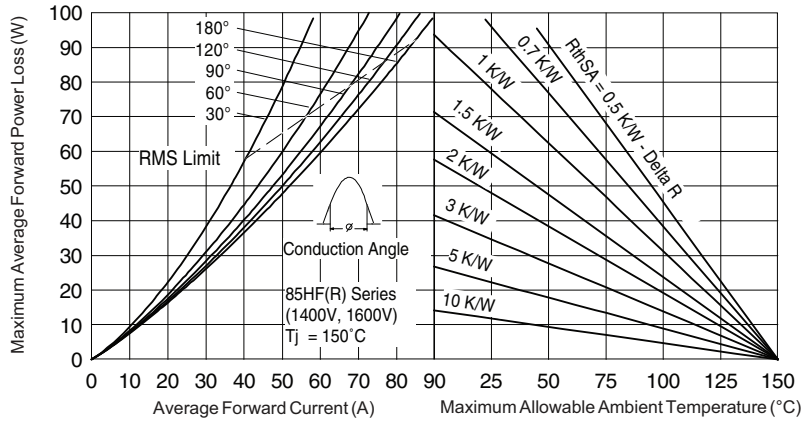


Fig. 7 - Forward Power Loss Characteristics

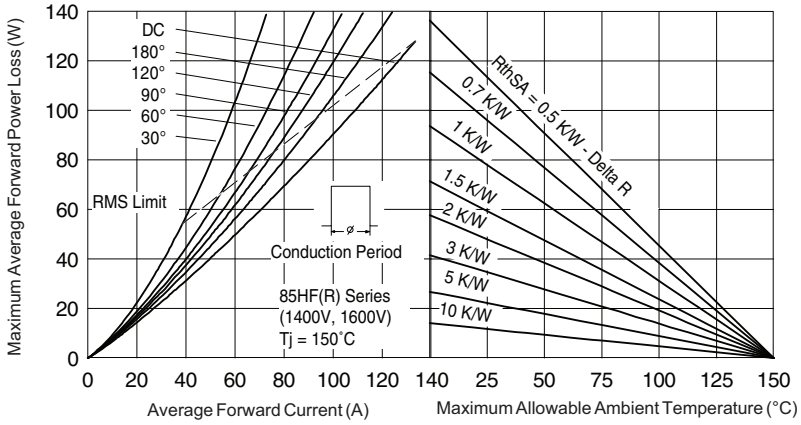


Fig. 8 - Forward Power Loss Characteristics

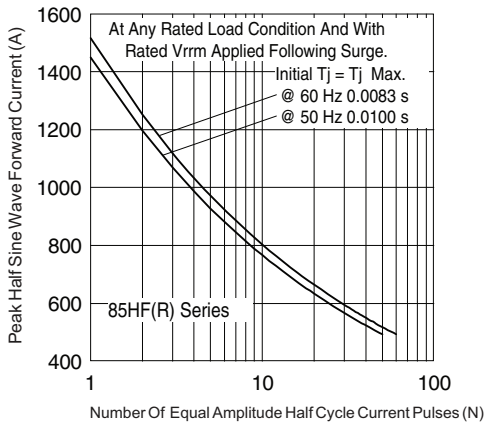


Fig. 9 - Maximum Non-Repetitive Surge Current

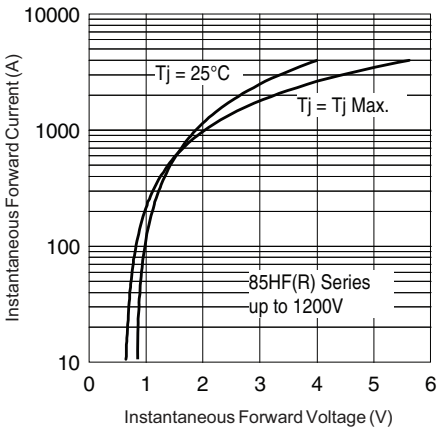


Fig. 11 - Forward Voltage Drop Characteristics
(up to 1200 V)

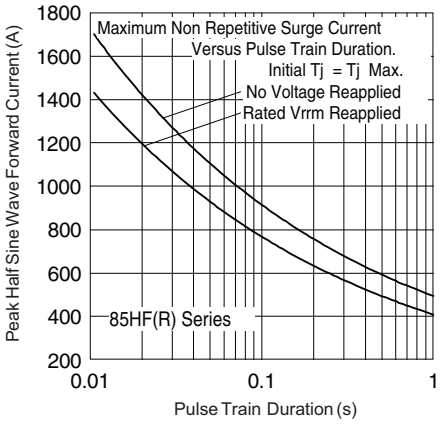


Fig. 10 - Maximum Non-Repetitive Surge Current

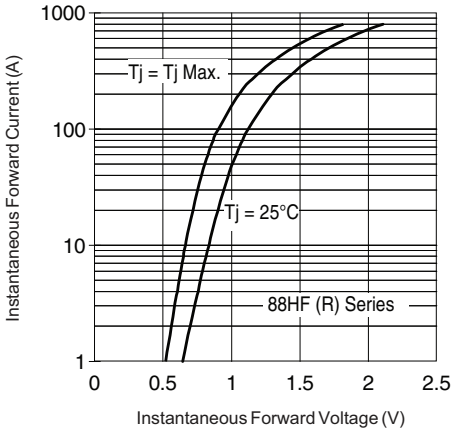


Fig. 12 - Forward Voltage Drop Characteristics
(for 1400 V, 1600 V)

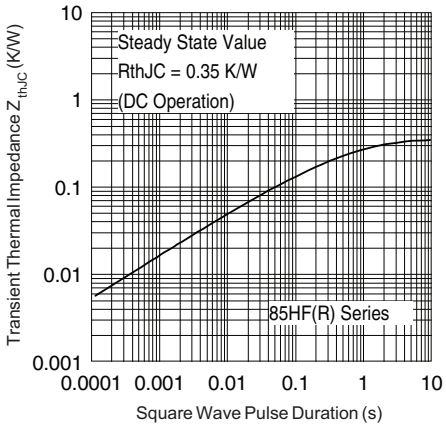


Fig. 13 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code

85	HF	R	160	M
1	2	3	4	5

1 - 85 = Standard device
86 = Not isolated lead
87 = Isolated lead with silicone sleeve
(red = Reverse polarity)
(blue = Normal polarity)
88 = Type for rotating application

2 - HF = Standard diode

3 - None = Stud normal polarity (cathode to stud)
R = Stud reverse polarity (anode to stud)

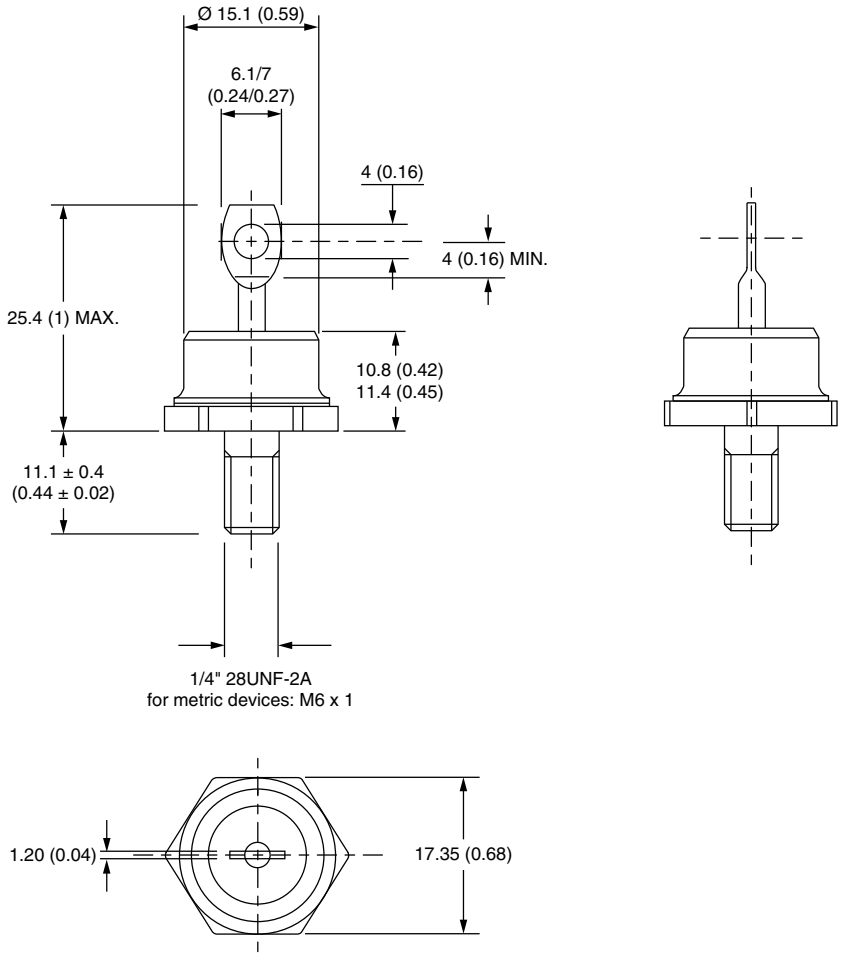
4 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

5 - None = Stud base DO-203AB (DO-5) 1/4" 28UNF-2A
M = Stud base DO-203AB (DO-5) M6 x 1 (not available for 88HF)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95342

DO-203AB (DO-5) for 85HF(R) and 86HF(R) Series

DIMENSIONS FOR 85HF(R) SERIES in millimeters (inches)

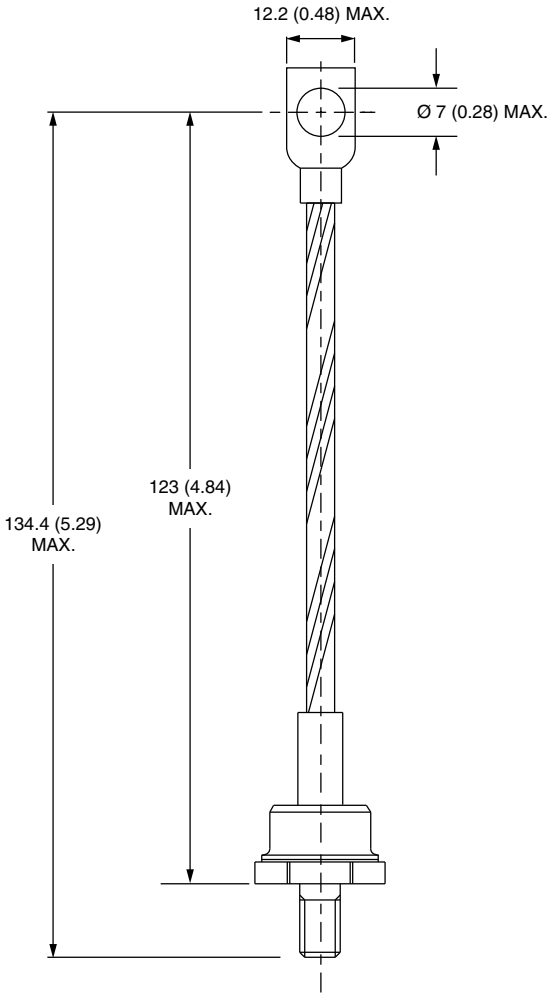


Outline Dimensions

Vishay Semiconductors

DO-203AB (DO-5) for 85HF(R)
and 86HF(R) Series

DIMENSIONS FOR 86HF(R) SERIES in millimeters (inches)



For technical questions, contact: indmodules@vishay.com

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay’s knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer’s responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer’s technical experts. Product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.